

# NPN Epitaxial Silicon Transistor

# **FJV1845**

#### **Amplifier Transistor**

• Complement to FJV992

#### ABSOLUTE MAXIMUM RATINGS (T<sub>a</sub> = 25°C unless otherwise noted)

| Symbol           | Rating                    | Value   | Unit |
|------------------|---------------------------|---------|------|
| V <sub>CBO</sub> | Collector-Base Voltage    | 120     | V    |
| V <sub>CEO</sub> | Collector–Emitter Voltage | 120     | V    |
| V <sub>EBO</sub> | Emitter-Base Voltage      | 5       | V    |
| I <sub>C</sub>   | Collector Current         | 50      | mA   |
| Ι <sub>Β</sub>   | Base Current              | 10      | mA   |
| PC               | Collector Dissipation     | 300     | mW   |
| TJ               | Junction Temperature      | 150     | °C   |
| T <sub>STG</sub> | Storage Temperature       | -55~150 | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### h<sub>FE2</sub> CLASSIFICATION

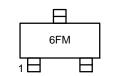
| Classification   | Р       | F       | E       | U        |
|------------------|---------|---------|---------|----------|
| h <sub>FE2</sub> | 200~400 | 300~600 | 400~800 | 600~1200 |



- 1. Base
- 2. Emitter
- 3. Collector

SOT-23 CASE 318

#### **MARKING DIAGRAM**



6 = Specific Device Code F = h<sub>FE</sub> Classification

M = Date Code

#### ORDERING INFORMATION

| Device      | Package                               | Shipping <sup>†</sup> |
|-------------|---------------------------------------|-----------------------|
| FJV1845FMTF | SOT-23<br>(Pb-Free /<br>Halogen Free) | 3000 / Tape &<br>Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **ELECTRICAL CHARACTERISTICS** (T<sub>a</sub> = 25°C unless otherwise noted)

| Symbol                               | Parameter                            | Test Condition   | Min        | Тур        | Max       | Unit |
|--------------------------------------|--------------------------------------|--|------------|------------|-----------|------|
| I <sub>CBO</sub>                     | Collector Cut-off Current            | V <sub>CB</sub> = 120 V, I <sub>E</sub> = 0  | _          | _          | 50        | nA   |
| I <sub>EBO</sub>                     | Emitter Cut-off Current              | $V_{EB} = 5 \text{ V}, I_{C} = 0$  | _          | _          | 50        | nA   |
| h <sub>FE1</sub><br>h <sub>FE2</sub> | DC Current Gain                      | $V_{CE} = 6 \text{ V}, I_{C} = 0.1 \text{ mA}$<br>$V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA}$ | 150<br>200 | 580<br>600 | _<br>1200 |      |
| V <sub>BE</sub> (on)                 | Base-Emitter On Voltage              | $V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA}$   | 0.55       | 0.59       | 0.65      | V    |
| V <sub>CE</sub> (sat)                | Collector–Emitter Saturation Voltage | $I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$  | _          | 0.07       | 0.3       | V    |
| f <sub>T</sub>                       | Current Gain Bandwidth Product       | $V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA}$   | 50         | 110        | _         | MHz  |
| C <sub>ob</sub>                      | Output Capacitance                   | $V_{CB} = 30 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$  | _          | 1.6        | 2.5       | pF   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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#### **FJV1845**

#### TYPICAL CHARACTERISTICS

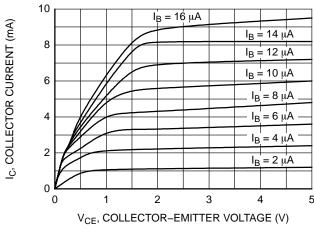


Figure 1. Static Characteristic

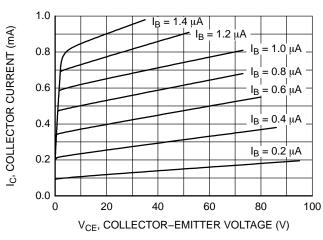


Figure 2. Static Characteristic

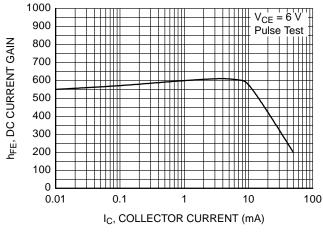


Figure 3. DC Current Gain

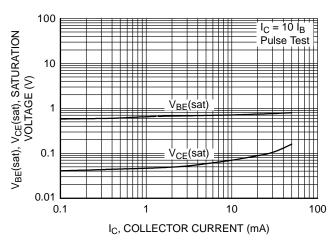


Figure 4. Base–Emitter Saturation Voltage Collector–Emitter Saturation Voltage

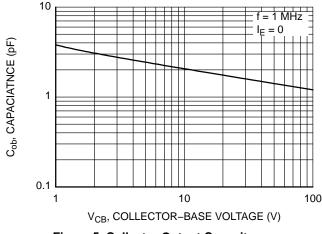


Figure 5. Collector Output Capacitance

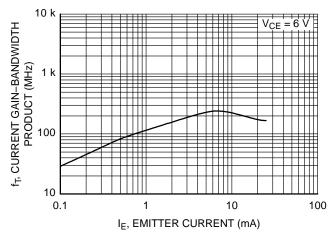
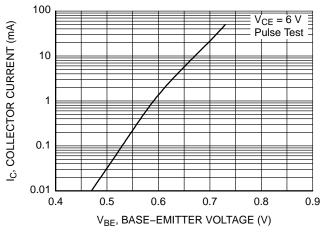
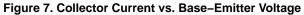


Figure 6. Current Gain Bandwidth Product

### **FJV1845**

# TYPICAL CHARACTERISTICS (continued)





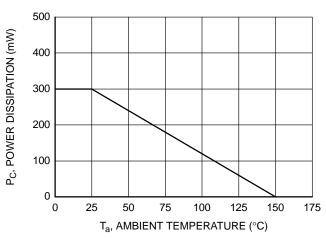


Figure 8. Power Derating

**MILLIMETERS** 

MIN

0.89

0.01

0.37

0.08

2.80

1.20

1.78

0.30

0.35

2.10

O°

NOM

1.00

0.06

0.44

0.14

2.90

1.30

1.90

0.43

0.54

2.40

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#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

**DATE 14 AUG 2024** 

MAX

1.11

0.10

0.50

0.20

3.04

1.40

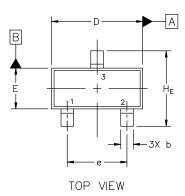
2.04

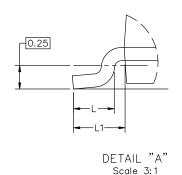
0.55

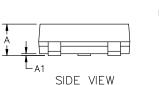
0.69

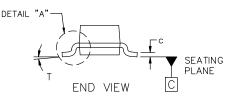
2.64

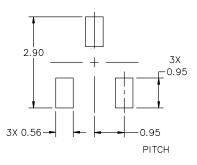
10°













DIM

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Α1

b

С

D

Ε

е L

L1

HE

Τ

- DIMENSIONING AND TOLERANCING 1. PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS:
- MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

# **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code

= Pb-Free Package



\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **STYLES ON PAGE 2**

| DOCUMENT NUMBER: | 98ASB42226B              | the Document Repository.  COPY" in red. |  |
|------------------|--------------------------|---|--|
| DESCRIPTION:     | SOT-23 (TO-236) 2.90x1.3 | SOT-23 (TO-236) 2.90x1.30x1.00 1.90P    |  |

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<sup>\*</sup>This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

## SOT-23 (TO-236) 2.90x1.30x1.00 1.90P CASE 318 ISSUE AU

DATE 14 AUG 2024

| STYLE 1 THRU 5:<br>CANCELLED                            | STYLE 6:<br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR | STYLE 7:<br>PIN 1. EMITTER<br>2. BASE<br>3. COLLECTOR | STYLE 8:<br>PIN 1. ANODE<br>2. NO CONNECTION<br>3. CATHODE | 1                |   |
|---|---|---|--|------------------|---|
| STYLE 9:  | STYLE 10:   | STYLE 11:   | STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE               | STYLE 13:        | STYLE 14:                                 |
| PIN 1. ANODE  | PIN 1. DRAIN  | PIN 1. ANODE  |  | PIN 1. SOURCE    | PIN 1. CATHODE                            |
| 2. ANODE  | 2. SOURCE   | 2. CATHODE  |  | 2. DRAIN         | 2. GATE                                   |
| 3. CATHODE  | 3. GATE   | 3. CATHODE-ANODE                                      |  | 3. GATE          | 3. ANODE                                  |
| STYLE 15:   | STYLE 16:   | STYLE 17:   | STYLE 18:  | STYLE 19:        | STYLE 20: PIN 1. CATHODE 2. ANODE 3. GATE |
| PIN 1. GATE   | PIN 1. ANODE  | PIN 1. NO CONNECTION                                  | PIN 1. NO CONNECTION                                       | N PIN 1. CATHODE |   |
| 2. CATHODE  | 2. CATHODE  | 2. ANODE  | 2. CATHODE   | 2. ANODE         |   |
| 3. ANODE  | 3. CATHODE  | 3. CATHODE  | 3. ANODE   | 3. CATHODE-ANODI |   |
| STYLE 21:   | STYLE 22:   | STYLE 23:   | STYLE 24:  | STYLE 25:        | STYLE 26:                                 |
| PIN 1. GATE   | PIN 1. RETURN   | PIN 1. ANODE  | PIN 1. GATE  | PIN 1. ANODE     | PIN 1. CATHODE                            |
| 2. SOURCE   | 2. OUTPUT   | 2. ANODE  | 2. DRAIN   | 2. CATHODE       | 2. ANODE                                  |
| 3. DRAIN  | 3. INPUT  | 3. CATHODE  | 3. SOURCE  | 3. GATE          | 3. NO CONNECTION                          |
| STYLE 27:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. CATHODE | STYLE 28:<br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE     |   |  |                  |   |

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| DESCRIPTION:     | SOT-23 (TO-236) 2.90x1.30x1.00 1.90P |  | PAGE 2 OF 2 |  |

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